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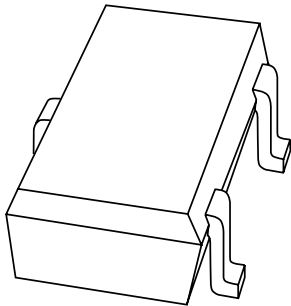
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Kind regards,

Team Nexperia

# DATA SHEET



## **PMSS3904** NPN switching transistor

Product data sheet  
Supersedes data of 1997 Sep 03

1999 May 27

## NPN switching transistor

## PMSS3904

## FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 40 V).

## APPLICATIONS

- General purpose switching and amplification
- Telephony and professional communication equipment.

## DESCRIPTION

NPN switching transistor in an SC-70 (SOT323) plastic package. PNP complement: PMSS3906.

## MARKING CODE

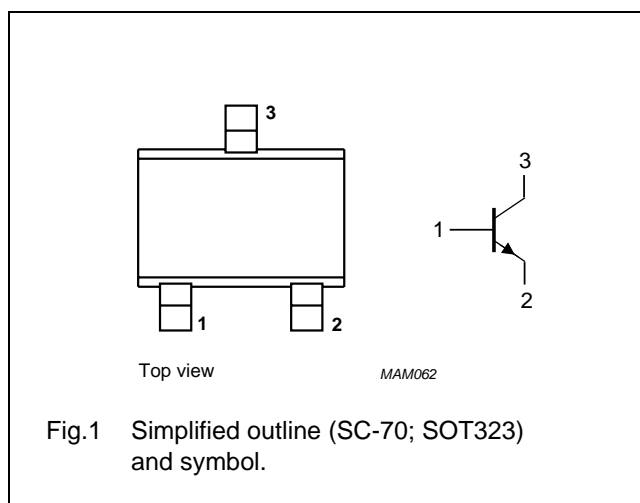
TYPE NUMBER	MARKING CODE <sup>(1)</sup>
PMSS3904	*04

## Note

- \* = - : Made in Hong Kong.  
\* = t : Made in Malaysia.

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	60	V
$V_{CEO}$	collector-emitter voltage	open base	–	40	V
$V_{EBO}$	emitter-base voltage	open collector	–	6	V
$I_C$	collector current (DC)		–	100	mA
$I_{CM}$	peak collector current		–	200	mA
$I_{BM}$	peak base current		–	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$ ; note 1	–	200	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## NPN switching transistor

## PMSS3904

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	625	K/W

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{CBO}$	collector cut-off current	$I_E = 0$ ; $V_{CB} = 30\text{ V}$	–	50	nA
		$I_E = 0$ ; $V_{CB} = 30\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	–	10	$\mu\text{A}$
$I_{EBO}$	emitter cut-off current	$I_C = 0$ ; $V_{EB} = 5\text{ V}$	–	50	nA
$h_{FE}$	DC current gain	$V_{CE} = 1\text{ V}$ ; see Fig.2			
		$I_C = 0.1\text{ mA}$	40	–	
		$I_C = 1\text{ mA}$	70	–	
		$I_C = 10\text{ mA}$	100	300	
		$I_C = 50\text{ mA}$ ; note 1	60	–	
		$I_C = 100\text{ mA}$ ; note 1	30	–	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}$ ; $I_B = 1\text{ mA}$	–	200	mV
		$I_C = 50\text{ mA}$ ; $I_B = 5\text{ mA}$ ; note 1	–	300	mV
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 10\text{ mA}$ ; $I_B = 1\text{ mA}$	650	850	mV
		$I_C = 50\text{ mA}$ ; $I_B = 5\text{ mA}$ ; note 1	–	950	mV
$C_c$	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 5\text{ V}$ ; $f = 1\text{ MHz}$	–	4	pF
$C_e$	emitter capacitance	$I_C = i_c = 0$ ; $V_{EB} = 0.5\text{ V}$ ; $f = 1\text{ MHz}$	–	12	pF
$f_T$	transition frequency	$I_C = 10\text{ mA}$ ; $V_{CE} = 20\text{ V}$ ; $f = 100\text{ MHz}$	180	–	MHz
F	noise figure	$I_C = 100\text{ }\mu\text{A}$ ; $V_{CE} = 5\text{ V}$ ; $R_S = 1\text{ k}\Omega$ $f = 10\text{ Hz to }15.7\text{ KHz}$	–	5	dB

## Switching times (between 10% and 90% levels); see Fig.3

$t_{on}$	turn-on time	$I_{Con} = 10\text{ mA}$ ; $I_{Bon} = 1\text{ mA}$ ; $I_{Boff} = -1\text{ mA}$ ; $V_{CC} = 3\text{ V}$ ; $V_{BB} = -1.9\text{ V}$	–	110	ns
$t_d$	delay time		–	50	ns
$t_r$	rise time		–	60	ns
$t_{off}$	turn-off time		–	1200	ns
$t_s$	storage time		–	1000	ns
$t_f$	fall time		–	200	ns

## Note

1. Pulse test:  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$ .

## NPN switching transistor

PMSS3904

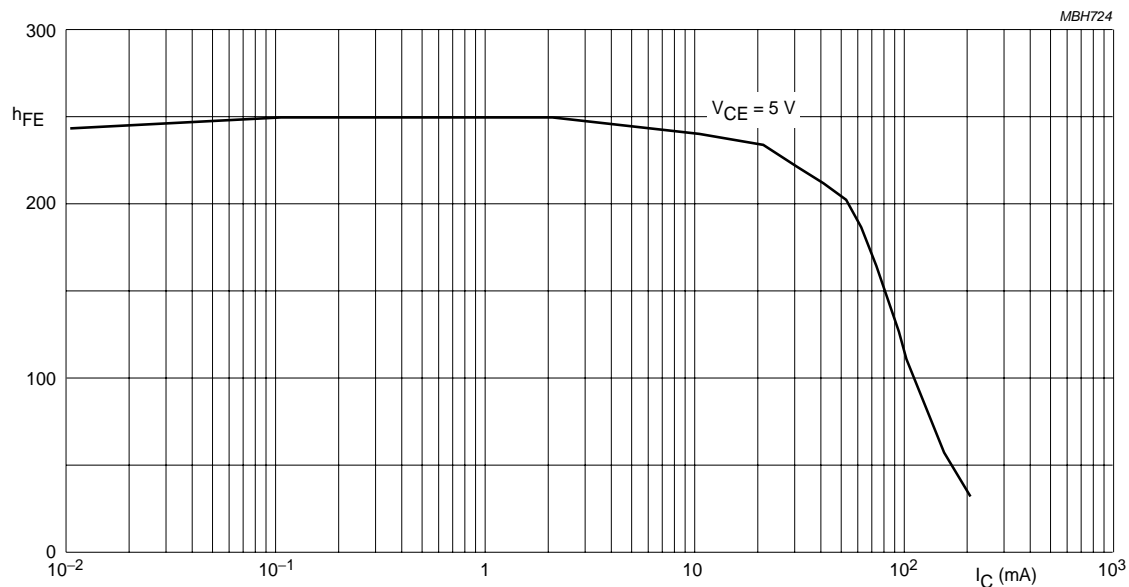
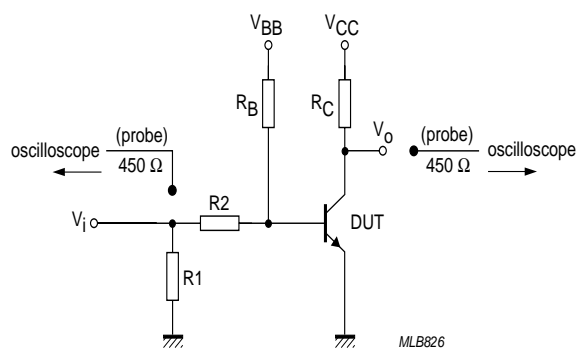


Fig.2 DC gain current; typical values.



$V_i = 5$  V;  $T = 500\ \mu\text{s}$ ;  $t_p = 10\ \mu\text{s}$ ;  $t_r = t_f \leq 3$  ns.  
 $R_1 = 56\ \Omega$ ;  $R_2 = 2.5\ \text{k}\Omega$ ;  $R_B = 3.9\ \text{k}\Omega$ ;  $R_C = 270\ \Omega$ .  
 Oscilloscope: input impedance  $Z_i = 50\ \Omega$ .

Fig.3 Test circuit for switching times.

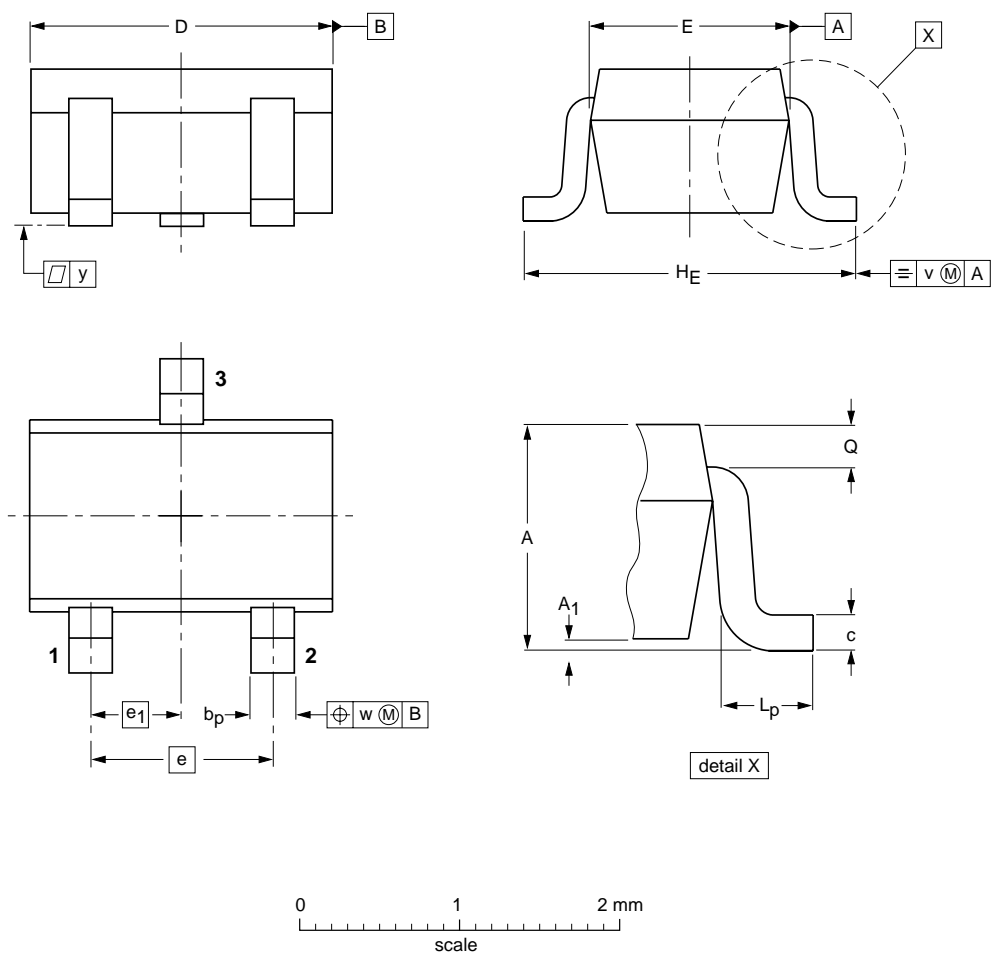
NPN switching transistor

PMSS3904

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A <sub>1</sub> max	b <sub>p</sub>	c	D	E	e	e <sub>1</sub>	H <sub>E</sub>	L <sub>p</sub>	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

**NPN switching transistor****PMSS3904****DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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## **Contact information**

For additional information please visit: **<http://www.nxp.com>**

For sales offices addresses send e-mail to: **[salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)**

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